# **ESD Protection Diode**

# Low Capacitance Array for High Speed **Data Lines**

# **ESD8704**

The ESD8704 is designed to protect high speed data lines from ESD. Ultra-low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines. The flow-through style package allows for easy PCB layout and matched trace lengths necessary to maintain consistent impedance between high speed differential lines such as USB 3.0/3.1.

#### **Features**

- Low Capacitance (0.5 pF Max, I/O to GND)
- Protection for the Following IEC Standards: IEC 61000-4-2 (Level 4)
- Low ESD Clamping Voltage
- SZESD8704MTWTAG Wettable Flank Package for optimal Automated Optical Inspection (AOI)
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

## **Typical Applications**

- USB 3.0/3.1
- eSATA
- DisplayPort

# **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	TL	260	°C
IEC 61000-4-2 Contact (ESD) IEC 61000-4-2 Air (ESD)	ESD ESD	±30 ±30	kV kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



## ON Semiconductor®

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## **MARKING DIAGRAM**



### UDFN10 CASE 517BB



7D = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

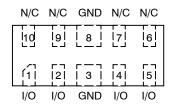


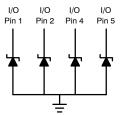
## WDFNW10 CASE 515AH



AAA = Specific Device Code = Date Code

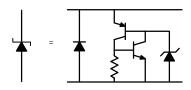
## PIN CONFIGURATION **AND SCHEMATIC**





Pins 3. 8

Note: Common GND - Only Minimum of 1 GND connection required



## **ORDERING INFORMATION**

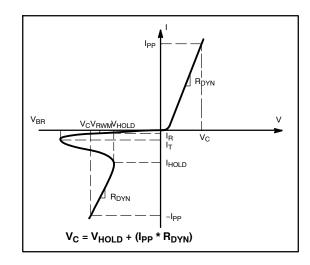
See detailed ordering, marking and shipping information in the package dimensions section on page 9 of this data sheet.

See Application Note AND8308/D for further description of survivability specs.

## **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

	,
Symbol	Parameter
V <sub>RWM</sub>	Working Peak Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current
V <sub>HOLD</sub>	Holding Reverse Voltage
I <sub>HOLD</sub>	Holding Reverse Current
R <sub>DYN</sub>	Dynamic Resistance
I <sub>PP</sub>	Maximum Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub> V <sub>C</sub> = V <sub>HOLD</sub> + (I <sub>PP</sub> * R <sub>DYN</sub> )



# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	$V_{RWM}$	I/O Pin to GND			3.3	V
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1 mA, I/O Pin to GND		5.0	6.0	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3 V, I/O Pin to GND			1.0	μΑ
Holding Reverse Voltage	V <sub>HOLD</sub>	I/O Pin to GND		1.9		V
Holding Reverse Current	I <sub>HOLD</sub>	I/O Pin to GND		20		mA
Clamping Voltage	V <sub>C</sub>	IEC61000-4-2, ±8 KV Contact				V
Clamping Voltage TLP	V <sub>C</sub>	I <sub>PP</sub> = 8 A I <sub>PP</sub> = -8 A		4.7 -4.0		V
		I <sub>PP</sub> = 16 A I <sub>PP</sub> = -16 A		6.6 -6.7		
Dynamic Resistance	R <sub>DYN</sub>	I/O Pin to GND GND to I/O Pin		0.30 0.38		Ω
Junction Capacitance	CJ	$V_R$ = 0 V, f = 1 MHz between I/O Pins and GND $V_R$ = 0 V, f = 2.5 GHz between I/O Pins and GND $V_R$ = 0 V, f = 5.0 GHz between I/O Pins and GND $V_R$ = 0 V, f = 1 MHz, between I/O Pins		0.30 0.30 0.31 0.15	0.50 0.40 0.40 0.25	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

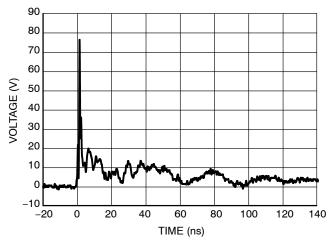


Figure 1. IEC61000-4-2 +8 kV Contact ESD Clamping Voltage

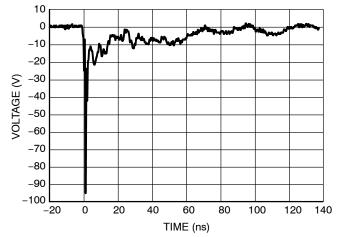


Figure 2. IEC61000-4-2 -8 kV Contact Clamping Voltage

## IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

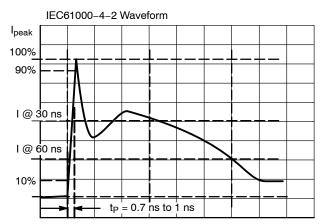


Figure 3. IEC61000-4-2 Spec

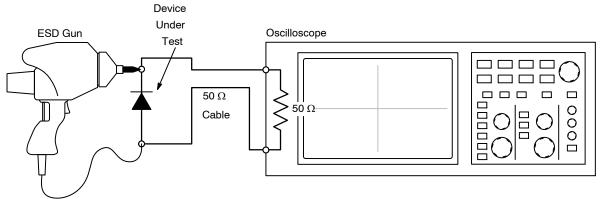


Figure 4. Diagram of ESD Clamping Voltage Test Setup

The following is taken from Application Note AND8307/D – Characterization of ESD Clamping Performance.

## **ESD Voltage Clamping**

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

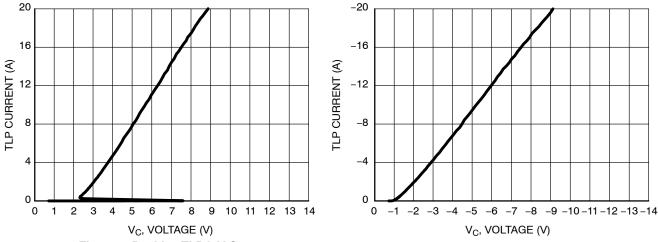


Figure 5. Positive TLP I-V Curve

Figure 6. Negative TLP I-V Curve

NOTE: TLP parameter:  $Z_0 = 50 \Omega$ ,  $t_p = 100$  ns,  $t_r = 300$  ps, averaging window:  $t_1 = 30$  ns to  $t_2 = 60$  ns.  $V_{IEC}$  is the equivalent voltage stress level calculated at the secondary peak of the IEC 61000–4–2 waveform at t = 30 ns with 2 A/kV. See TLP description below for more information.

## Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 7. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 8 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to AND9007/D.

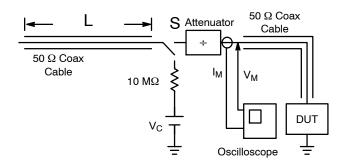


Figure 7. Simplified Schematic of a Typical TLP System

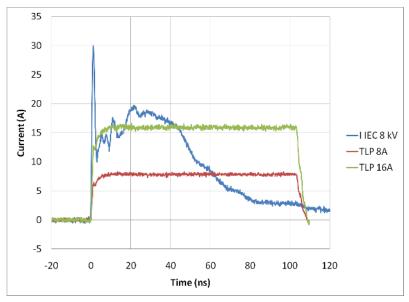


Figure 8. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

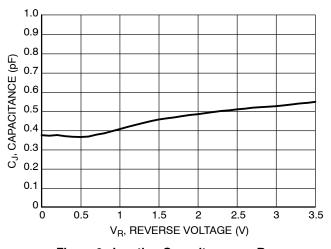


Figure 9. Junction Capacitance vs. Reverse Voltage

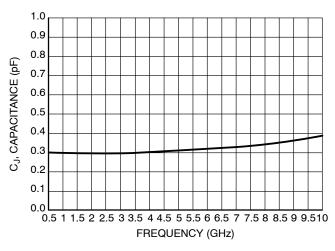
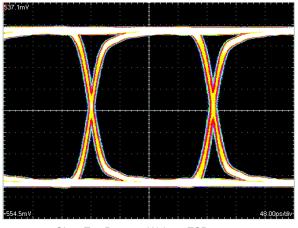
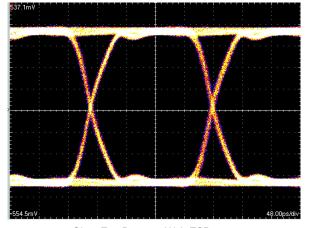


Figure 10. Junction Capacitance vs. Frequency

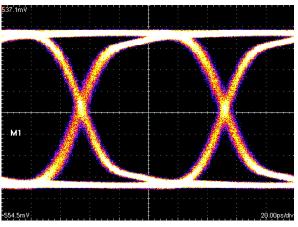


5 Gbps Eye Diagram Without ESD8704

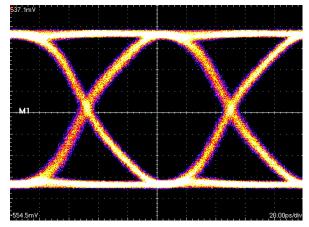


5 Gbps Eye Diagram With ESD8704

Figure 11. USB3.0 Eye Diagram with and without ESD8704. 5 Gb/s



10 Gbps Eye Diagram Without ESD8704



10 Gbps Eye Diagram With ESD8704

Figure 12. USB3.1 Eye Diagram with and without ESD8704. 10 Gb/s

See application note AND9075/D for further description of eye diagram testing methodology.

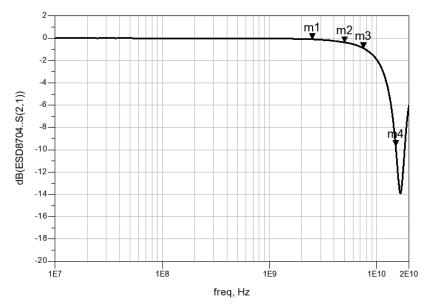


Figure 13. ESD8704 Insertion Loss

Interface	Data Rate (Gb/s)	Fundamental Frequency (GHz)	3 <sup>rd</sup> Harmonic Frequency (GHz)	ESD8704 Insertion Loss (dB)
USB 3.0	5	2.5 (m1)	7.5 (m3)	m1 = -0.09 m3 = -0.89
USB 3.1	10	5.0 (m2)	15 (m4)	m2 = -0.36 m4 = -9.68

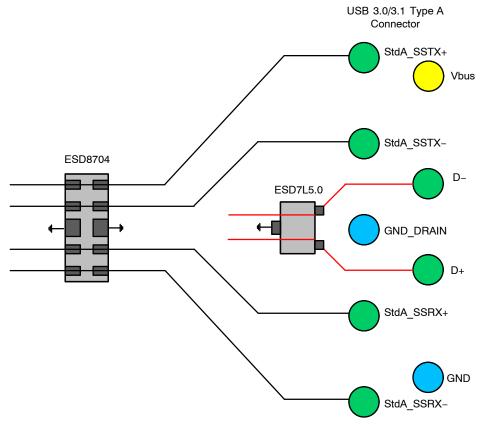


Figure 14. USB 3.0/3.1 Standard Layout Diagram

## **PCB Layout Guidelines**

Steps must be taken for proper placement and signal trace routing of the ESD protection device in order to ensure the maximum ESD survivability and signal integrity for the application. Such steps are listed below.

- Place the ESD protection device as close as possible to the I/O connector to reduce the ESD path to ground and improve the protection performance.
  - In USB 3.0 applications, the ESD protection device should be placed between the AC coupling capacitors and the I/O connector on the TX differential lanes as shown in Figure 15. In this configuration, no DC current can flow through the ESD protection device preventing any potential

latch-up condition. For more information on latchup considerations, see below description on Page 8.

- Make sure to use differential design methodology and impedance matching of all high speed signal traces.
  - Use curved traces when possible to avoid unwanted reflections.
  - Keep the trace lengths equal between the positive and negative lines of the differential data lanes to avoid common mode noise generation and impedance mismatch.
  - Place grounds between high speed pairs and keep as much distance between pairs as possible to reduce crosstalk.

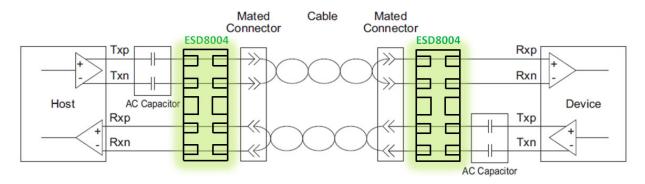


Figure 15. USB 3.0/3.1 Connection Diagram

#### **Latch-Up Considerations**

ON Semiconductor's 8000 series of ESD protection devices utilize a snap-back, SCR type structure. By using this technology, the potential for a latch-up condition was taken into account by performing load line analyses of common high speed serial interfaces. Example load lines for latch-up free applications and applications with the potential for latch-up are shown below with a generic IV characteristic of a snapback, SCR type structured device overlaid on each. In the latch-up free load line case, the IV characteristic of the snapback protection device intersects the load-line in one unique point ( $V_{\rm OP}$   $I_{\rm OP}$ ). This is the only stable operating point of the circuit and the system is

therefore latch-up free. Please note that for USB 3.0 applications, ESD8704 latch-up free considerations are explained in more detail in the above PCB layout guidelines. In the non-latch up free load line case, the IV characteristic of the snapback protection device intersects the load-line in two points (V<sub>OPA</sub>, I<sub>OPA</sub>) and (V<sub>OPB</sub>, I<sub>OPB</sub>). Therefore in this case, the potential for latch-up exists if the system settles at (V<sub>OPB</sub>, I<sub>OPB</sub>) after a transient. Because of this, ESD8704 should not be used for HDMI applications – ESD8104 or ESD8040 have been designed to be acceptable for HDMI applications without latch-up. Please refer to Application Note AND9116/D for a more in-depth explanation of latch-up considerations using ESD8000 series devices.

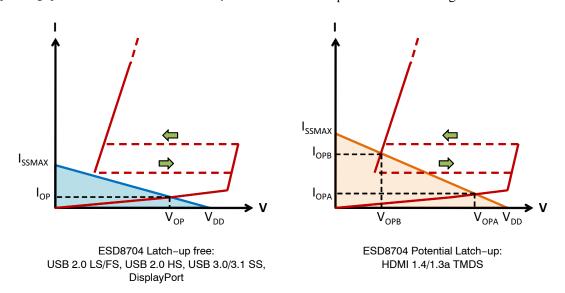


Figure 16. Example Load Lines for Latch-up Free Applications and Applications with the Potential for Latch-up

Table 1. SUMMARY OF SCR REQUIREMENTS FOR LATCH-UP FREE APPLICATIONS

Application	VBR (min) (V)	IH (min) (mA)	VH (min) (V)	ON Semiconductor ESD8000 Series Recommended PN
HDMI 1.4/1.3a TMDS	3.465	54.78	1.0	ESD8104, ESD8040
USB 2.0 LS/FS	3.301	1.76	1.0	ESD8704
USB 2.0 HS	0.482	N/A	1.0	ESD8704
USB 3.0/3.1 SS	2.800	N/A	1.0	ESD8704, ESD8006
DisplayPort	3.600	25.00	1.0	ESD8704, ESD8006

## **DEVICE ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
ESD8704MUTAG	7D	UDFN10 (Pb-Free)	3000 / Tape & Reel
SZESD8704MUTAG	7D	UDFN10 (Pb-Free)	3000 / Tape & Reel
SZESD8704MTWTAG	AAA	WDFNW10 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# WDFNW10 2.5x1.0, 0.5P

CASE 515AH ISSUE B

**DATE 03 AUG 2020** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- DIMENSION 6 APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
- DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.70	0.75	0.80	
A1	0.00		0.05	
A3	ĺ	0.20 REF	-	
Α4	0.10	-	-	
b	0.15	0.20	0.25	
b2	0.35	0.40	0.45	
D	2.40	2.50	2.60	
Е	0.90	1.00	1.10	
e	0.50 BSC			
L	0.30	0.35	0.40	
L3			0.10	

- CONTROLLING DIMENSION: MILLIMETERS
- .15 AND 0.30MM FROM THE TERMINAL TIP.
- THIS DEVICE CONTAINS WETTABLE FLANK

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.70	0.75	0.80	
A1	0.00		0.05	
A3	ĺ	0.20 REF	-	
Α4	0.10	-		
ھ	0.15	0.20	0.25	
b2	0.35	0.40	0.45	
D	2.40	2.50	2.60	
E	0.90	1.00	1.10	
e	0.50 BSC			
L	0.30	0.35	0.40	
L3			0.10	

# **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

PIN DNE REFERENCE	В		N□TE: 1.
	E 1	L3—A4	A3 2. C
TOP VIEW		PLATED	0. 4. (
DETAIL B	-A	SURFACE SECTION (	C-C Pr
// 0.10 C	П	67	5. 1 Di F
O.08 C C NOTE 4 SIDE VIEW	C PLA	ATING ANE	
	L	1 (C) (C)	L L 3
E   -   -   -   8x b   0.10   0.00	DICIAIBI 51ci	DETA	ALTERNATE CONSTRUCTION IL A
B□TT□M VIEW	NOTE 3		
PACKAGE 1.60  8X0.25	PLATED SURFACE	EXPOSED COPPER  A1  PLATED SURFACE	ALTERNATE ALTERNATE
RECOMMENDED MOUNTING FOOTPRINT		DETAIL	CONSTRUCTION
For additional information on our Pb-Free stra soldering details, please download the DN Senice Soldering and Mounting Techniques Reference Mo	tegy and onductor anual,		

Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

**DOCUMENT NUMBER:** 98AON08744H

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**DESCRIPTION:** WDFNW10 2.5x1.0, 0.5P PAGE 1 OF 1

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# **MECHANICAL CASE OUTLINE**



## UDFN10 2.5x1, 0.5P CASE 517BB-01 **ISSUE 0**

C SEATING PLANE

10X L

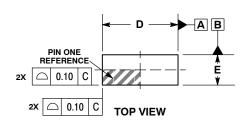
**DATE 17 NOV 2009** 



0.10 C

0.08 C

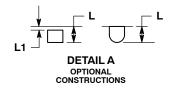
DETAIL A

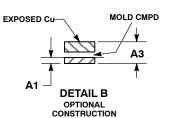


DETAIL B

SIDE VIEW

2X **b2** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER
   ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM TERMINAL.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
A3	0.13	REF		
b	0.15	0.25		
b2	0.35	0.45		
D	2.50 BSC			
Е	1.00 BSC			
е	0.50 BSC			
L	0.30	0.40		
L1		0.05		

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code М

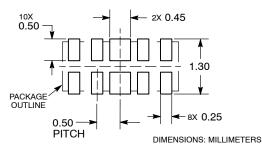
= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

#### 8x b CAB 0.10 Ф С 0.05 NOTE 3 **BOTTOM VIEW**

## **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	UDFN10 2.5X1, 0.5P		PAGE 1 OF 1	

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